

PNP SURFACE MOUNT SMALL SIGNAL TRANSISTOR IN SOT323
Features

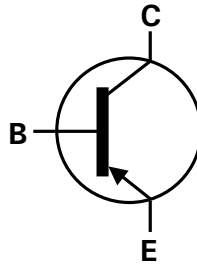
- Ideally Suited for Automatic Insertion
- Complementary NPN Types Available (BC846W – BC848W)
- For switching and AF Amplifier Applications
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

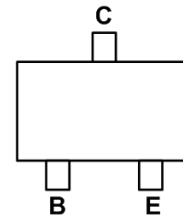
- Case: SOT323
- Case material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight: 0.006 grams (Approximate)



Top View



Device Symbol

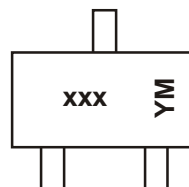

 Top View
Pin-Out

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Quantity per reel
BC856AW-7-F	K3A	7	3,000
BC856BW-7-F	K3B	7	3,000
BC856BW-13-F	K3B	13	10,000
BC857AW-7-F	K3A	7	3,000
BC857BW-7-F	K3B	7	3,000

Product	Marking	Reel size (inches)	Quantity per reel
BC857CW-7-F	K3G	7	3,000
BC858AW-7-F	K3A	7	3,000
BC858BW-7-F	K3B	7	3,000
BC858CW-7-F	K3G	7	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Tape width is 8mm. For more packaging details, go to our website at <http://www.diodes.com>.

Marking Information


xxx = Product Type Marking Code
 (Please see Ordering Information)
 YM = Date Code Marking
 Y = Year (ex: X = 2010)
 M = Month (ex: 9 = September)

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
		-50	
		-30	
Collector-Emitter Voltage	V _{CEO}	-65	V
		-45	
		-30	
Emitter-Base Voltage	V _{EBO}	-5.0	V
Continuous Collector Current	I _C	-100	mA
Peak Collector Current	I _{CM}	-200	mA
Peak Emitter Current	I _{EM}	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	200	mW
Thermal Resistance, Junction to Ambient	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-80	-	-	V	I _C = -100nA
		-50				
		-30				
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	-65	-	-	V	I _C = -10mA
		-45				
		-30				
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	-	-	V	I _E = -100nA
DC Current Gain (Note 6)	h _{FE}	125	180	250	-	V _{CE} = -5.0V, I _C = -2.0mA
		220	290	475		
		420	520	800		
Collector Cutoff Current	I _{CBO}	-	-	-15	nA	V _{CB} = -30V
				-4	μA	V _{CB} = -30V, T _A = +150°C
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	-	-75	-300	mV	I _C = -10mA, I _B = -0.5mA
			-250	-650		I _C = -100mA, I _B = -5.0mA
Base-Emitter Turn-On Voltage (Note 6)	V _{BE(on)}	-	-600	-650	mV	I _C = -2mA, V _{CE} = -5V
			-	-820		I _C = -10mA, V _{CE} = -5V
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	-	-700	-	mV	I _C = -10mA, I _B = -0.5mA
			-850	-950		I _C = -100mA, I _B = -5mA
Output Capacitance	C _{obo}	-	3	4.5	pF	V _{CB} = -10V, f = 1.0MHz
Transition Frequency	f _T	100	200	-	MHz	V _{CE} = -5V, I _C = -10mA, f = 100MHz
Noise Figure	NF	-	-	10	dB	V _{CE} = -5V, I _C = -200μA R _S = 2kΩ, f = 1kHz Δf = 200Hz

Notes: 5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition; the device is measured when operating in a steady-state condition.
6. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

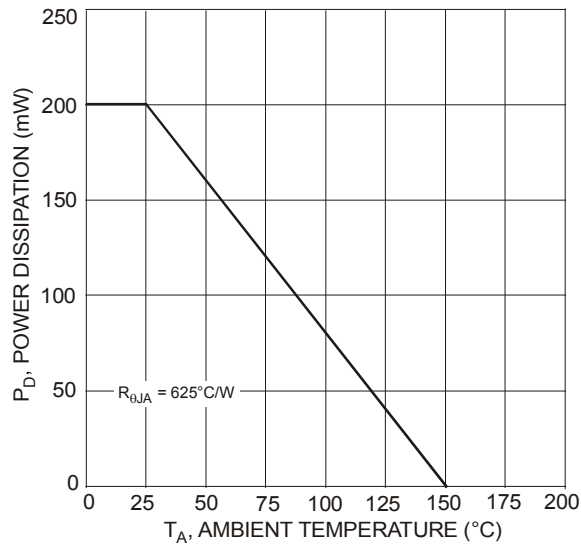


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 5)

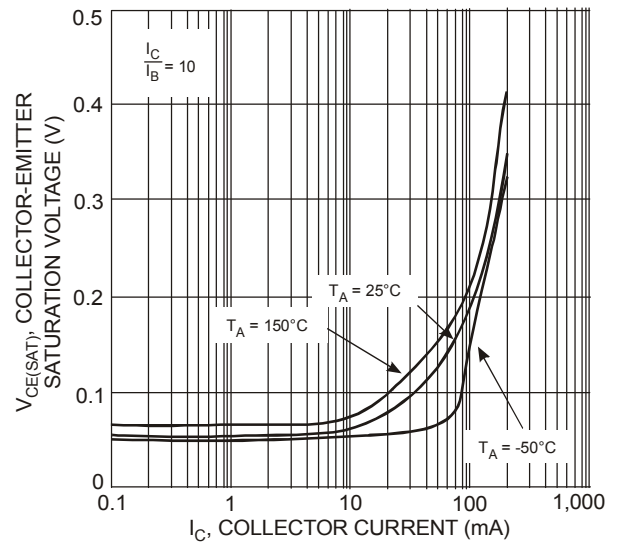


Fig. 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

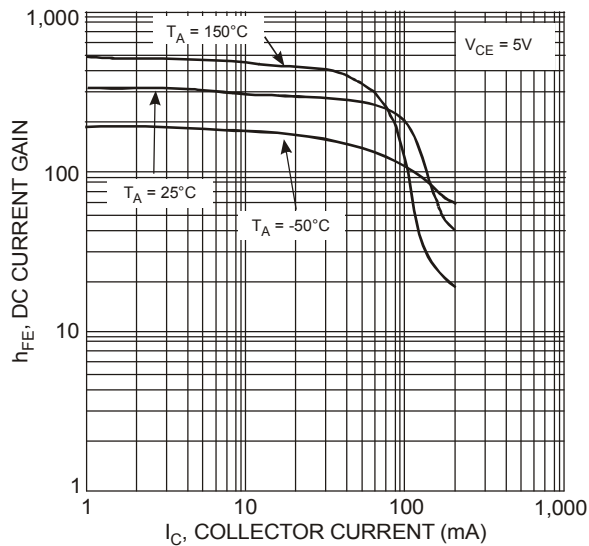


Fig. 3 Typical DC Current Gain (Group B) vs. Collector Current

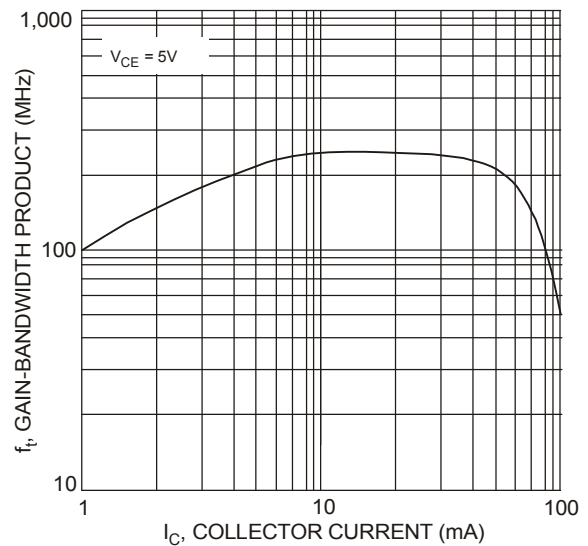
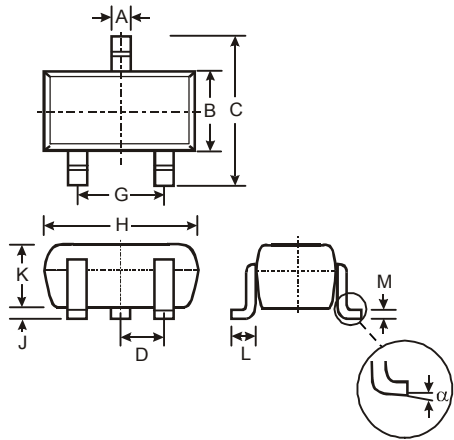


Fig. 4 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

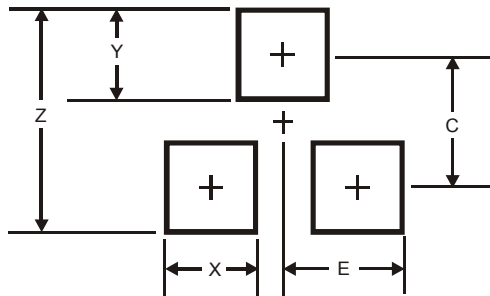
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT323			
Dim	Min	Max	Typ
A	0.25	0.40	0.30
B	1.15	1.35	1.30
C	2.00	2.20	2.10
D	-	-	0.65
G	1.20	1.40	1.30
H	1.80	2.20	2.15
J	0.0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
M	0.10	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.8
X	0.7
Y	0.9
C	1.9
E	1.0

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